Excellent Integrated System Limited

Stocking Distributor

Click to view price, real time Inventory, Delivery & Lifecycle Information:

Rohm Semiconductor
2SK2731T146

For any questions, you can email us directly:
sales@integrated-circuit.com

Interface and switching (30V, 200mA)

2SK2731

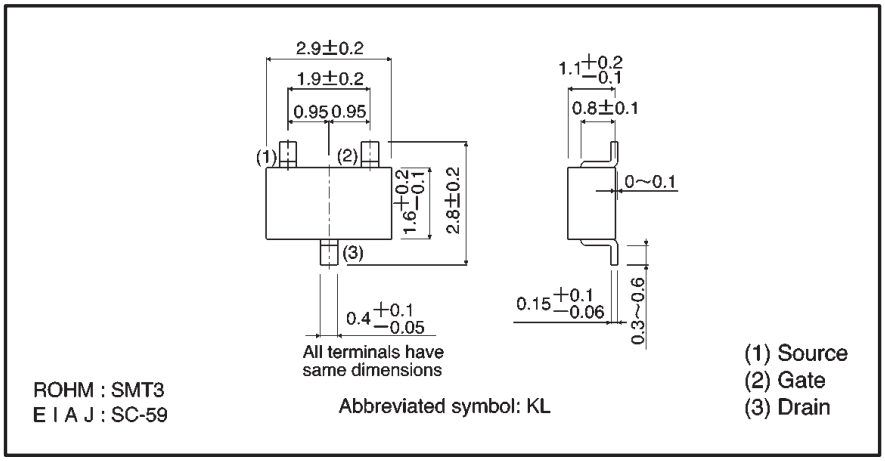
●Features

1) Low on-resistance.
2) Fast switching speed.
3) Low-voltage drive (4V).
4) Easily designed drive circuits.
5) Easy to parallel.

●Structure

Silicon N-channel
MOSFET

●External dimensions (Units: mm)

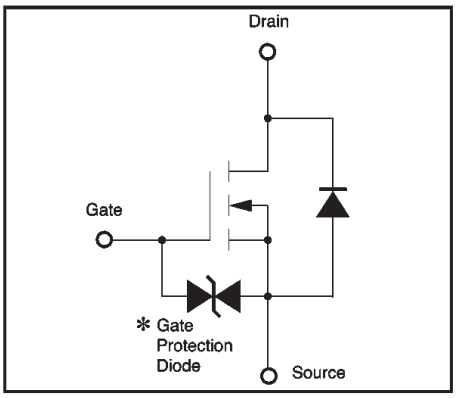


●Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	30	V
Gate-source voltage		V_{GSS}	±20	V
Drain current	Continuous	I_D	200	mA
	Pulsed	I_{DP}*	800	mA
Reverse drain current	Continuous	I_{DR}	200	mA
	Pulsed	I_{DRP}*	800	mA
Total power dissipation		P_D	200	mW
Channel temperature		Tch	150	℃
Storage temperature		Tstg	−55~+150	℃

* Pw≦10 μs, Duty cycle≦1%

●Equivalent circuit



* A protection diode is included between the gate and the source terminals to protect the diode against static electricity when the product is in use.Use a protection circuit when the fixed voltage are exceeded.

●Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Gate-source leakage	I_{GSS}	—	—	±10	μA	V_{GS}=±20V, V_{DS}=0V
Drain-source breakdown voltage	$V_{(BR)\,DSS}$	30	—	—	V	I_D=1mA, V_{GS}=0V
Zero gate voltage drain current	I_{DSS}	—	—	10	μA	V_{DS}=30V, V_{GS}=0V
Gate threshold voltage	$V_{GS\,(th)}$	1.0	—	2.5	V	V_{DS}=10V, I_D=1mA
Static drain-source on-state resistance	$R_{DS\,(on)}$	—	1.5	2.8	Ω	I_D=0.1A, V_{GS}=10V
		—	2.8	4.5		I_D=0.1A, V_{GS}=4V
Forward transfer admittance	$\|Y_{fs}\|$*	100	—	—	mS	I_D=0.1A, V_{DS}=10V
Input capacitance	C_{iss}	—	25	—	pF	V_{DS}=10V
Output capacitance	C_{oss}	—	15	—	pF	V_{GS}=0V
Reverse transfer capacitance	C_{rss}	—	10	—	pF	f=1MHz
Turn-on delay time	$t_{d\,(on)}$	—	15	—	ns	I_D=0.1A, V_{DD}≒15V
Rise time	t_r	—	20	—	ns	V_{GS}=10V
Turn-off delay time	$t_{d\,(off)}$	—	90	—	ns	R_L=150Ω
Fall time	t_f	—	100	—	ns	R_G=10Ω

* Pw≦300 μs, Duty cycle≦1%

●Packaging specifications

Type	Package	Taping
	Code	T146
	Basic ordering unit (pieces)	3000
2SK2731		○

●Electrical characteristic curves

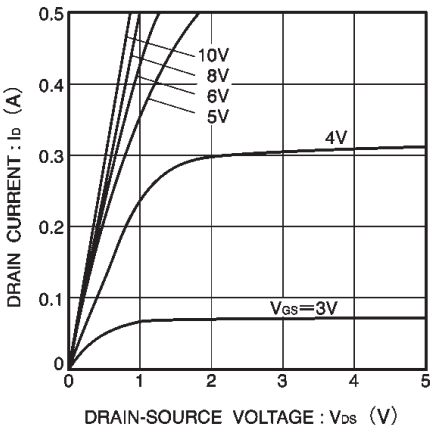


Fig.1 Typical output characteristics

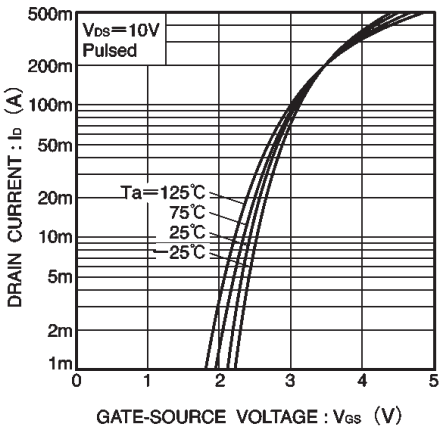


Fig.2 Typical transfer characteristics

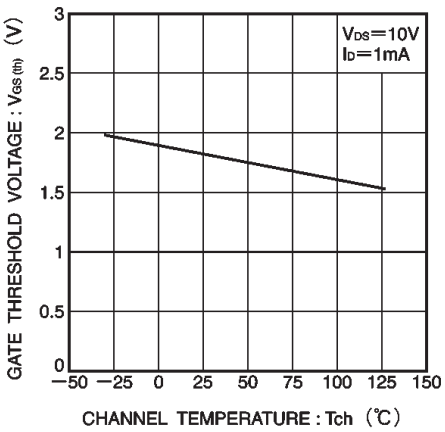


Fig.3 Gate threshold voltage vs. channel temperature

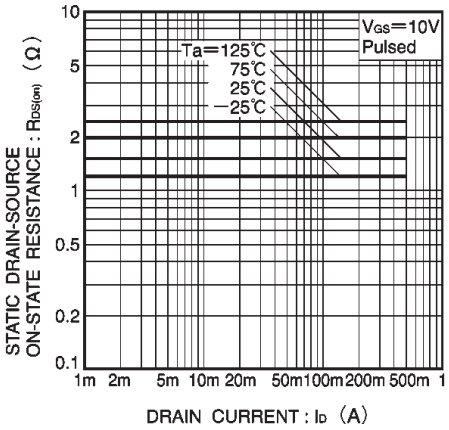


Fig.4 Static drain-source on-state resistance vs. drain current (Ⅰ)

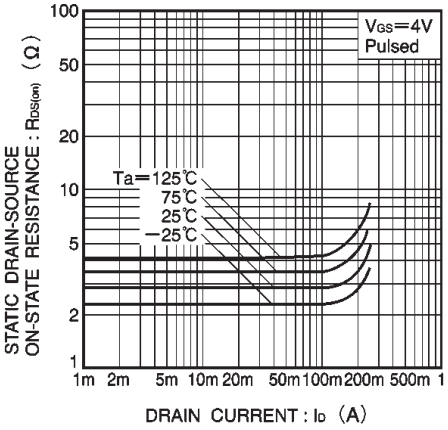


Fig.5 Static drain-source on-state resistance vs. drain current (Ⅱ)

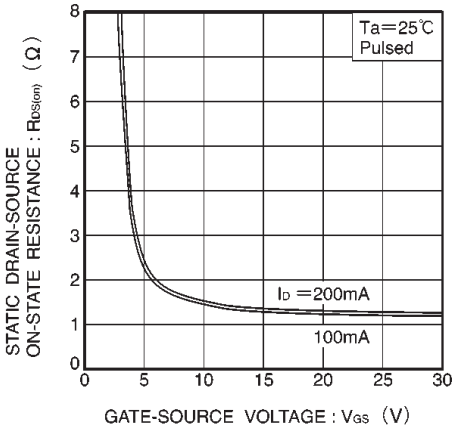


Fig.6 Static drain-source on-state resistance vs. gate-source voltage

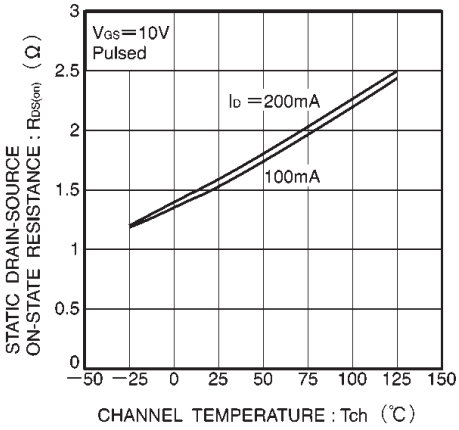


Fig.7 Static drain-source on-state resistance vs. channel temperature

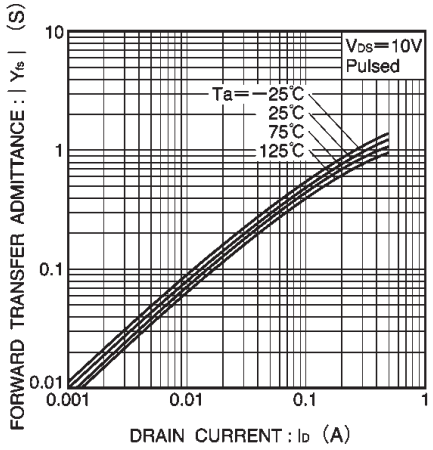


Fig.8 Forward transfer admittance vs. drain current

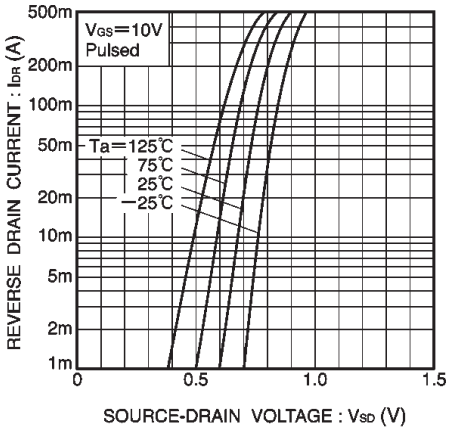


Fig.9 Reverse drain current vs. source-drain voltage (Ⅰ)

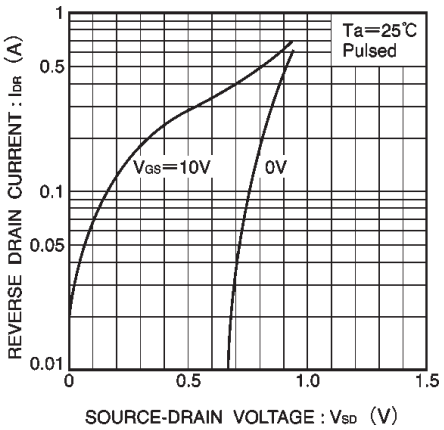


Fig.10 Reverse drain current vs. source-drain voltage (Ⅱ)

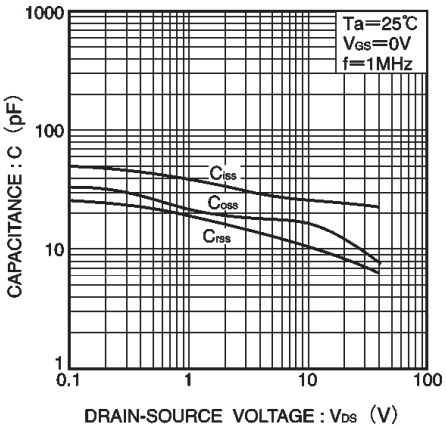


Fig.11 Typical capacitance vs. drain-source voltage

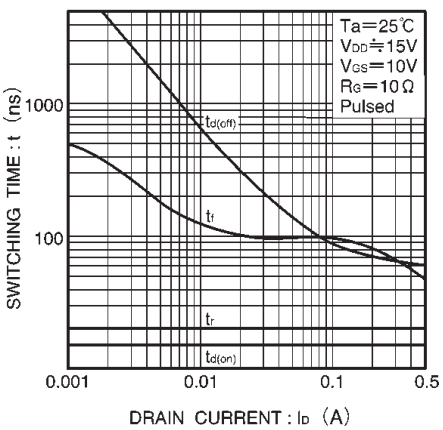


Fig.12 Switching characteristics (See Figures 13 and 14 for the measurement circuit and resultant waveforms)

●Switching characteristics measurement circuit

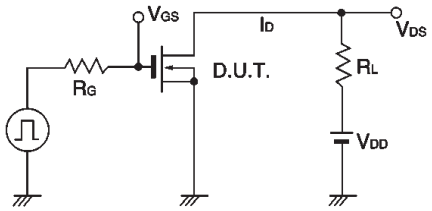


Fig.13 Switching time measurement circuit

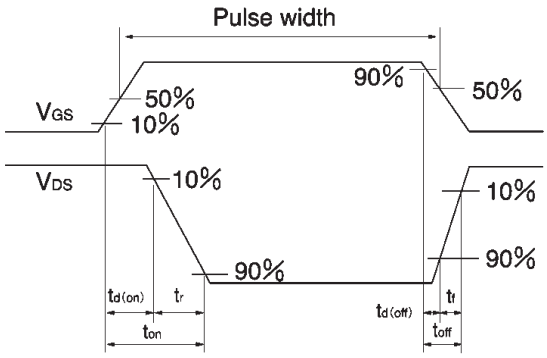


Fig.14 Switching time waveforms

Appendix

Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document use silicon as a basic material.
  Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).
Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of with would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.
In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.